10/654,767

## **SPECIFICATION**

Please amend the first paragraph of the specification as follows:

This application is a continuation-in-part of United States application number 10/158,946 filed May 31, 2002, now United States patent number 6,709,230, issued on March 23, 2004.

Please amend the paragraph beginning on page 9, line 14 as follows:

The present invention may be embodied with a variety of materials provided that the two aggregate materials exhibit sufficiently different coefficients of thermal expansion so that thermal stresses generated there between during heating of the material result in a degree of micro cracking within the aggregation sufficient to achieve a desired degree of strain tolerance in the material. For example, the aggregate material having the higher CTE may be any of the rare earth oxides, tetragonal zirconia t-ZrO<sub>2</sub> (such as 8YSZ), alumina Al<sub>2</sub>O<sub>3</sub>, magnesia MgO, or spinel MgAl<sub>2</sub>O<sub>4</sub>, and/or the aggregate material having the lower CTE may be mullite 3Al<sub>2</sub>O<sub>3</sub>?2SiO<sub>2</sub>, 3Al<sub>2</sub>O<sub>3</sub>2SiO<sub>2</sub>, zircon ZrSiO<sub>4</sub>, an alkaline earth aluminosilicate such as cordierite 2MgO ?2Al<sub>2</sub>O<sub>3</sub> ?5SiO<sub>2</sub> 2MgO 2Al<sub>2</sub>O<sub>3</sub> 5SiO<sub>2</sub> or celsian BaO ?Al<sub>2</sub>O<sub>3</sub> ?2SiO<sub>2</sub>, BaO Al<sub>2</sub>O<sub>3</sub> 2SiO<sub>2</sub>, or a low CTE non-oxide such as silicon carbide SiC or silicon nitride Si<sub>3</sub>N<sub>4</sub>.